

BTA06T-600CWRG

6 A Snubberless™ Triac

Features

- High static and dynamic commutation
- BTA series is UL1557 certified (File ref.: 81734)
- Package is RoHS (2002/95/EC) compliant
- I_{GT} = 35 mA

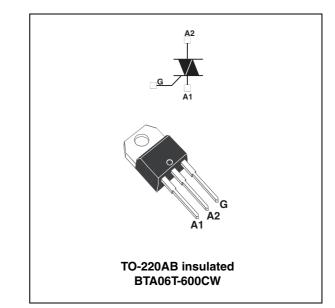
Applications

Specially designed for power tool applications, it can also be used to drive loads like motor speed controller, kitchen equipments such as electro valves, light dimmers and similar.

Description

Available in through-hole package, the Triac BTA06T-600CW is suitable for general purpose ac switching.

Being a fully insulated package, the BTA06T-600CW provides insulation rated at 2500 V rms.



TM: Snubberless is a trademark of STMicroelectronics

1 Characteristics

Symbol	Parameter			Value	Unit
I _{T(RMS)}	On-state rms current (full sine wave)		T _c = 100 °C	6	А
I	avela size wave. T initial 05 °C	F = 60 Hz	t = 16.7 ms	47	А
I _{TSM}		F = 50 Hz	t = 20 ms	45	A
l²t	I ² t Value for fusing	t _p = 10 ms		13	A ² s
dl/dt	$ \begin{array}{ c c c } Critical rate of rise of on-state current \\ I_G = 2 \ x \ I_{GT}, \ t_r \leq 100 \ ns \end{array} \end{array} \begin{array}{ c c } F = 120 \ Hz \end{array} \begin{array}{ c } T_j = 125 \ ^\circ C \end{array} $		50	A/µs	
V _{DSM} /V _{RSM}	Non repetitive surge peak off-state voiltage $t_p = 10 \text{ ms}$ $T_j = 25 \text{ °C}$		V _{DRM} /V _{RRM} + 100	V	
I _{GM}	Peak gate current $t_p = 20 \ \mu s$ $T_j = 125 \ ^{\circ}C$		4	А	
P _{G(AV)}	Average gate power dissipation $T_j = 125 \text{ °C}$		1	W	
T _{stg} T _j	Storage junction temperature range Operating junction temperature range			-40 to +150 -40 to +125	°C

Table 1. Absolute maximum ratings (limiting values)

Table 2.Electrical characteristics, Snubberless (3 quadrants) $(T_i = 25 °C, unless otherwise specified)$

Symbol	Test conditions	Quadrant		Value	Unit	
I _{GT} ⁽¹⁾	$V_D = 12 \text{ V R}_L = 30 \Omega$	- -	MAX	35	mA	
V _{GT}	$V_D = 12 \text{ V R}_L = 30 \Omega$	- -	MAX	1.3	V	
V_{GD}	$V_D = V_{DRM} R_L = 3.3 \text{ k}\Omega$	- -	MIN	0.2	V	
I _H ⁽²⁾	I _T = 100 mA		MAX	35	mA	
1		I - III	MAX	50	mA	
۱ _L	$I_{G} = 1.2 \times I_{GT}$		WIAA	80	ША	
dV/dt ⁽²⁾	$V_D = 67\% V_{DRM}$, gate open, $T_j = 125 \text{ °C}$			750	V/µs	
(dl/dt)c ⁽²⁾	Without snubber, T _j = 125 °C			8.0	A/ms	

1. Minimum I_{GT} is guaranteed at 5% of I_{GT} max.

2. For both polarities of A2 pin referenced to A1 pin

Table 3. Static electrical characteristics

Symbol	ol Test conditions			Value	Unit
V _{TM} ⁽¹⁾	I _{TM} = 8.5 A, t _p = 380 μs	T _j = 25 °C	MAX	1.6	V
V _{TO} ⁽¹⁾	Threshold voltage	T _j = 125 °C	MAX	0.85	V
R _D ⁽¹⁾	Dynamic resistance	T _j = 125 °C	MAX	80	mΩ
I _{DRM}	<u> </u>	T _j = 25 °C	МАХ	5	μA
I _{RRM}	V _{DRM} = V _{RRM}	T _j = 125 °C		1	mA

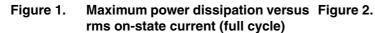
1. For both polarities of A2 pin referenced to A1 pin

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Symbol	Parameter		Unit
R _{th(j-c)}	Junction to case (ac)	3.4	°C/W
R _{th(j-a)}	Junction to ambient	60	0/11

Table 4. **Thermal resistances**



On-state current (rms) versus case temperature (full cycle)

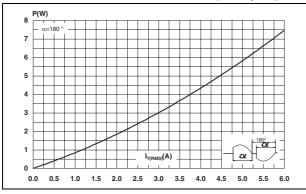


Figure 3. On-state current (rms) versus ambient temperature (free air convection)

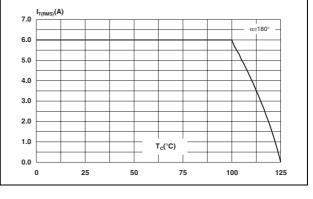


Figure 4. **Relative variation of thermal**

 $K=[Z_{th}/R_{th}]$

1.E+00

1.E-01

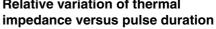
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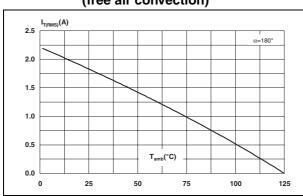
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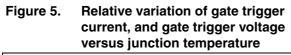
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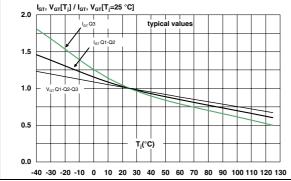
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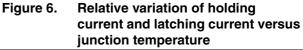
1.E-01











t_P(s)

1.E+00

1.E+01

1.E+02

1.E+03

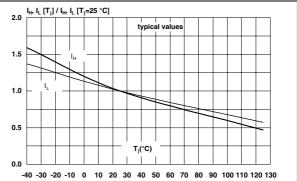
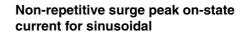




Figure 7. Surge peak on-state current versus Figure 8. number of cycles



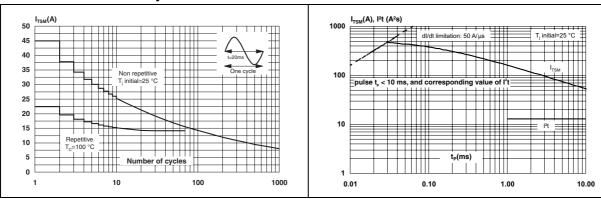


Figure 9. On-state characteristics (maximum values)

Figure 10. Relative variation of critical rate of decrease of main current (di/dt)c versus junction temperature

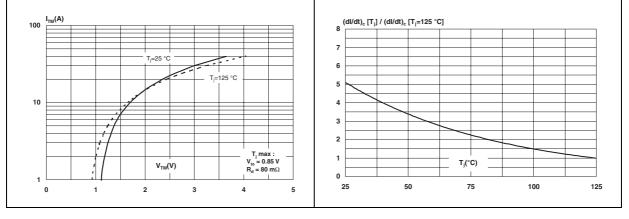
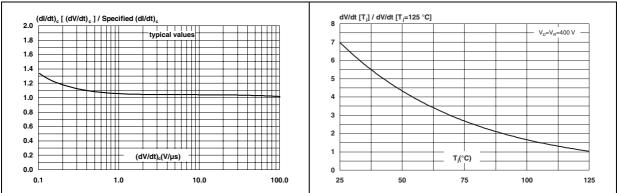


Figure 11. Relative variation of critical rate of decrease of main current (di/dt)c versus reapplied (dV/dt)c

Figure 12. Relative variation of static dV/dt immunity versus junction temperature





2 Ordering information

Figure 13. Ordering information scheme

	BT A 06 T - 600	CW RG
Triac series		
Insulation A = Insulated		
Current 06 = 6 A		
Specific application		
Voltage 600 = 600 V		
Sensitivity and type C = 35 mA, W = Snubberless		
Packing mode RG = Tube		



3 Package information

- Epoxy meets UL94, V0
- Lead-free packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK[®] is an ST trademark.

Table 5. TO-220AB insulated dimensions

					Dimer	nsions		
		Ref.	Mi	illimete	rs		Inches	
			Min.	Тур.	Max.	Min.	Тур.	Max.
		А	15.20		15.90	0.598		0.625
		a1		3.75			0.147	
В	с	a2	13.00		14.00	0.511		0.551
ØI	b2	В	10.00		10.40	0.393		0.409
		b1	0.61		0.88	0.024		0.034
	F	b2	1.23		1.32	0.048		0.051
A		С	4.40		4.60	0.173		0.181
14 13 ···(¹ / ₁)-		c1	0.49		0.70	0.019		0.027
	c2	c2	2.40		2.72	0.094		0.107
		e	2.40		2.70	0.094		0.106
a2		F	6.20		6.60	0.244		0.259
	M =	ØI	3.75		3.85	0.147		0.151
t t t t t t t t t t t t t t t t t t t		14	15.80	16.40	16.80	0.622	0.646	0.661
e		L	2.65		2.95	0.104		0.116
		12	1.14		1.70	0.044		0.066
		13	1.14		1.70	0.044		0.066
		М		2.60			0.102	

4 Ordering information

Table 6. Ordering information

Order code	Order code Marking		Weight	Base qty	Packing mode
BTA06T-600CWRG BTA06T-600CW		TO-220AB ins	2.3 g	50	Tube

5 Revision history

Table 7.Document revision history

Date	Revision	Changes
15-Nov-2007	1	Initial release.
17-Jun-2010 2		Updated title on page 1. Updated ECOPACK statement.



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